

H. How much excitation (phonons) at temperature T?

(a) Single Oscillator Statistical Physics

$e_\omega = \underbrace{\langle n \rangle}_{\text{temperature dependent}} \hbar\omega + \frac{1}{2} \hbar\omega = \text{mean energy of an oscillator of characteristic freq. } \omega \text{ when it is at equilibrium at temperature } T$

$$\langle n \rangle(T) = \frac{1}{e^{\hbar\omega/kT} - 1} \quad (31)$$

mean # phonons for a mode ω [$\omega(q)$] at temp. T

single oscillator partition function

Remark:

$$\rightarrow Z = \sum_{n=0}^{\infty} e^{-\beta(n\hbar\omega + \frac{\hbar\omega}{2})} = e^{-\frac{\beta}{2}\hbar\omega} \sum_{n=0}^{\infty} e^{-n(\beta\hbar\omega)} = e^{-\frac{\beta}{2}\hbar\omega} \frac{1}{1 - e^{-\beta\hbar\omega}}$$

$$u = -\frac{\partial}{\partial \beta} \ln Z = \frac{1}{2} \hbar\omega + \frac{\hbar\omega}{e^{\hbar\omega/kT} - 1} = \frac{1}{2} \hbar\omega + \langle n \rangle \hbar\omega$$

high temperature behavior: ($kT \gg \hbar\omega$)

$$\text{single oscillator energy} = \underbrace{\frac{1}{2}\hbar\omega}_{\text{G.S.}} + \underbrace{kT}_{\text{equipartition (two quadratic terms)}}$$

$$\frac{\hbar\omega}{(1 + \frac{\hbar\omega}{kT}) - 1} = kT$$

low temperature behavior: ($kT < \hbar\omega$)

$$\text{single oscillator energy} = \frac{1}{2}\hbar\omega + \underbrace{\hbar\omega e^{-\hbar\omega/kT}}_{\text{not much}}$$

(b) All Branches and all modes

$$E = \underbrace{U_0}_{\text{G.S.}} + \sum_s \sum_{\vec{q}} \frac{\hbar \omega_s(\vec{q})}{e^{\hbar \omega_s(\vec{q})/kT} - 1} \quad (32)$$

High temperature limit: ($kT \gg$ all ω 's)

$$E = U_0 + \underbrace{3rN}_{\text{atoms/unit cell}} kT$$

$r = \#$ atoms/unit cell

$3r = \#$ of branches [3 acoustic plus optical]

$N = \#$ unit cells in crystal

$kT =$ "equipartition of energy"

$$C = \text{Heat capacity} = \frac{\partial E}{\partial T} = 3rNk \quad (33)$$

per mole, then $N_A k = R$ gas constant
↓

Called Dulong-Petit Law

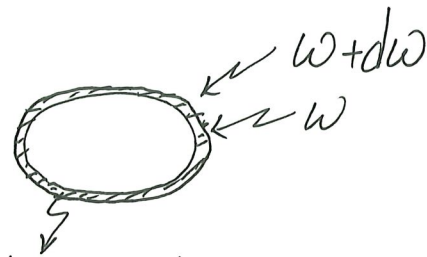
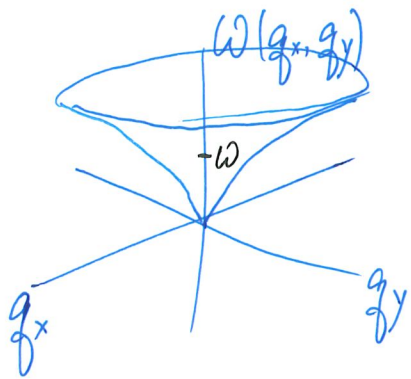
(c) Density of modes ($D(\omega) d\omega$)

Similar to density of electronic states, want to count

normal modes in interval $\omega \rightarrow \omega + d\omega$

can do it branch by branch, then add results

Cut at $\omega \Rightarrow$ constant- ω surface [for a dispersion relation]



Area (Volume) enclosed \propto # \vec{q} 's $\Rightarrow \propto$ # modes

$$D(\omega) = \frac{V}{(2\pi)^3} \oint \frac{dS_\omega}{|\nabla_{\vec{q}} \omega(\vec{q})|}$$

for each branch, then add results

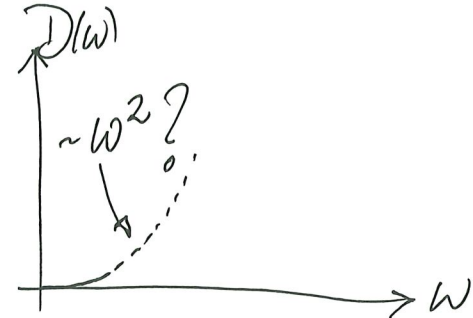
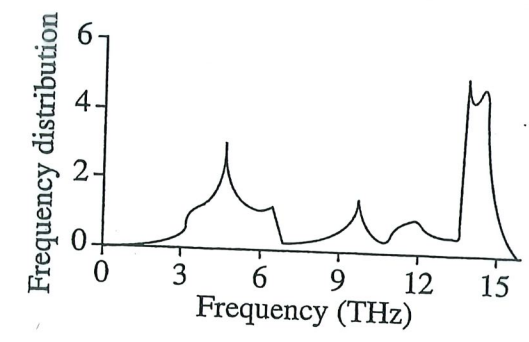
over surface (in \vec{q} -space) of constant- ω

Need numerical schemes to count $D(\omega)$

- sharp features come from flatter parts of $\omega(\vec{q})$ and/or overlapping branches

- Critical points in $D(\omega)$
 (places $|\nabla_{\vec{q}} \omega(\vec{q})| \approx 0$)

- Low frequency part

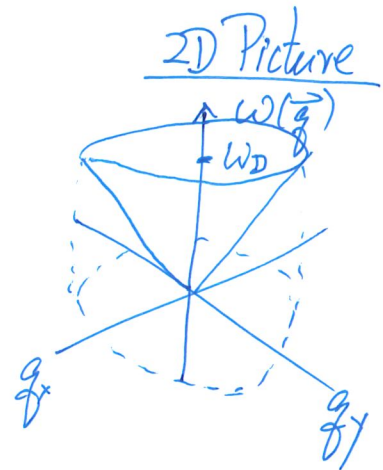



Frequency distribution function versus frequency for Si

Debye approximation

Acoustic branches : $\omega \sim v_s q$ ($q \rightarrow 0$)

- Keep $\omega \sim v_s q$ form beyond small q
- Keep N modes per branch



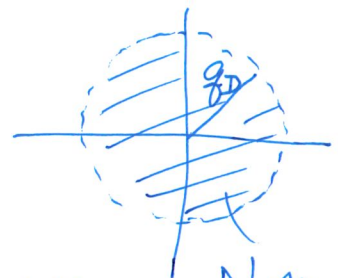
$$D(\omega) d\omega = \frac{V}{(2\pi)^3} \cdot 4\pi q^2 dq = \frac{V}{2\pi^2} \cdot \frac{\omega^2}{v_s^3} d\omega$$

$$\therefore D(\omega) = \frac{V}{2\pi^2} \frac{1}{v_s^3} \cdot \omega^2$$

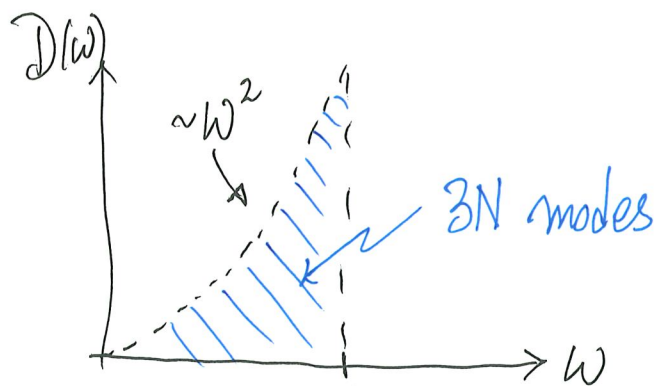
Two TA and One LA branches:

$$D(\omega) = \frac{V}{2\pi^2} \left(\frac{2}{v_t^3} + \frac{1}{v_l^3} \right) \omega^2 = \frac{V}{2\pi^2} \frac{3}{v_0^3} \cdot \omega^2 \quad (34)$$

slope of that branch
 3 identical ($\omega = v_0 q$) branches [equivalently]



N modes for the branch



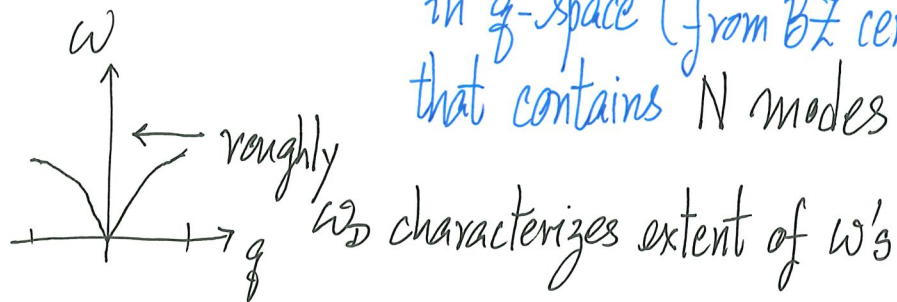
$$\int_0^{\omega_D} D(\omega) d\omega = 3N \Rightarrow \omega_D = \left(6\pi^2 \frac{N}{V}\right)^{1/3} v_0$$

$$\equiv \underbrace{f_D}_{\text{radius}} \cdot v_0$$

meaning: Radius of sphere in q -space (from BZ center out) that contains N modes

Debye frequency ω_D need a cutoff

ω_D is a property of material



$$\hbar\omega_D \equiv k\theta_D$$

θ_D Debye temperature [set temperature scale of lattice vibrations]

Si	658 K
Ge	366 K
GaAs	345 K
InSb	200 K

} IR (just like molecular vibrational frequencies)

$\omega_D \leftrightarrow g_D \leftrightarrow \theta_D$ (same thing expressed differently)

$$D(\omega) = \frac{9N}{\omega_D^3} \cdot \underbrace{\omega^2}_{\sim \omega^{D-1}} \quad 0 < \omega < \omega_D \quad \text{if expressed in } \omega_D \quad \text{Debye approximation}$$

(D is dimension)

Now energy at temperature T becomes

$$E(T) = U_0 + \int D(\omega) \frac{\hbar\omega}{e^{\hbar\omega/kT} - 1} d\omega$$

(exact) when $D(\omega)$ contains contributions from all branches

$$= U_0 + \frac{9N}{\omega_D^3} \int_0^{\omega_D} \omega^2 \frac{\hbar\omega}{e^{\hbar\omega/kT} - 1} d\omega$$

(Debye approximation) [acoustic branches]

(35)

gives $\underbrace{3NkT}$ at $kT \gg \hbar\omega_D$ (high temp limit)
 $C \sim 3Nk$ (observed)

$$E(T) = U_0 + a T^4$$

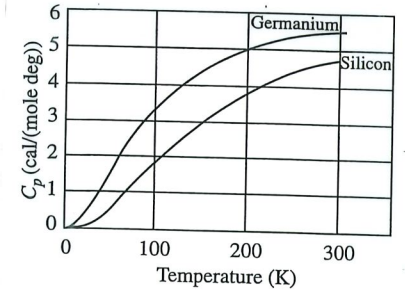
$\underbrace{\quad}_{\leftarrow kT \ll \hbar \omega_D} \text{ (low temp.)}$

Hence $C \sim \left(\frac{T}{\Theta_D}\right)^3 \cdot Nk$ (low temp.) [observed]

(36)

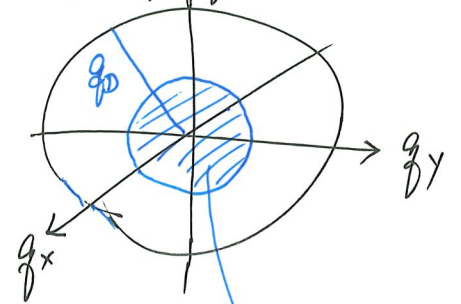
Physical Picture

modes excited per branch at temp. $T \sim N \cdot \left(\frac{T}{\Theta_D}\right)^3$



Specific heat of Si and Ge versus absolute temperature

OR in q -space

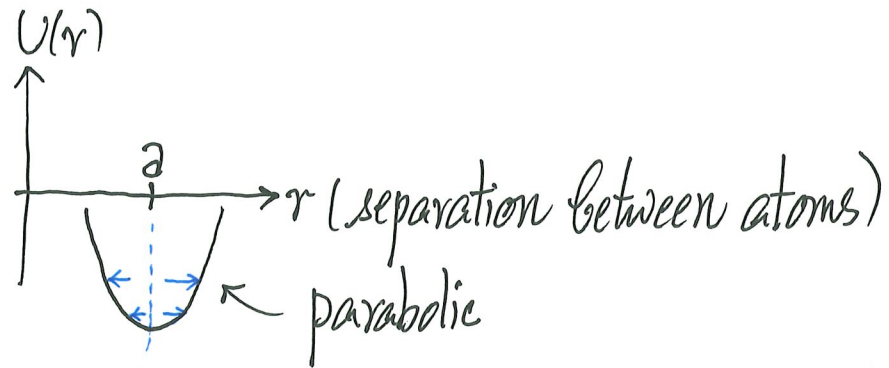


modes excited at temp. T
 $q_{upper} \sim \left(\frac{kT}{\hbar \nu_0}\right)$

I. Anharmonic Effects

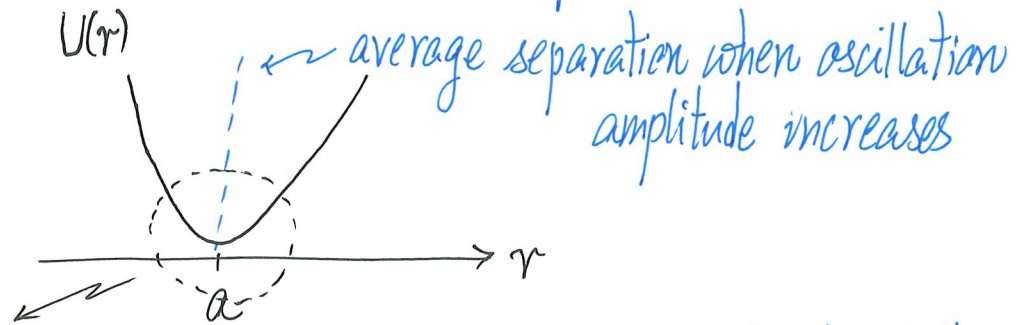
(a) Thermal Expansion

Harmonic Approximation



high T , large amplitude, but mean separation = a
 \Rightarrow no thermal expansion

Anharmonic



Consider $U = c \underbrace{(r-a)^2}_{x^2} - \gamma \underbrace{(r-a)^3}_{x^3}$

Average separation at $T = a + \frac{3\gamma}{4c^2} kT = a \left(1 + \frac{3\gamma k}{4c^2 a} \right) T$

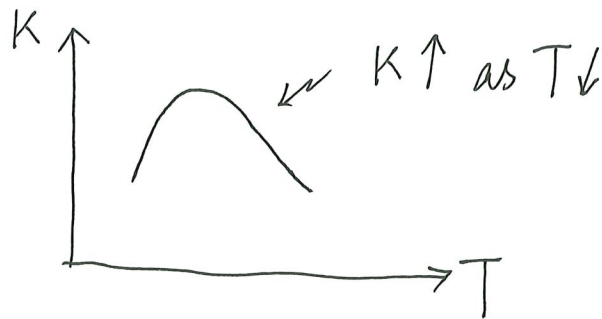
an estimate of thermal expansion coefficient

(b) Thermal Conductivity

$$\frac{dQ}{dt} = k \cdot A \cdot \left(-\frac{dT}{dx} \right) \quad (36)$$

rate of heat flow (J/s or W) \leftarrow $\frac{dQ}{dt}$
 thermal conductivity (Wm⁻¹K⁻¹) \leftarrow a property of matter
 cross sectional area across which heat flows (m²) \leftarrow A
 negative of temperature gradient (K/m) \leftarrow $\left(-\frac{dT}{dx} \right)$
 "-" sign: heat flows from high temp. to low temp.

Features for insulators/semiconductors (free carriers ignored)



This is a typical linear response idea.

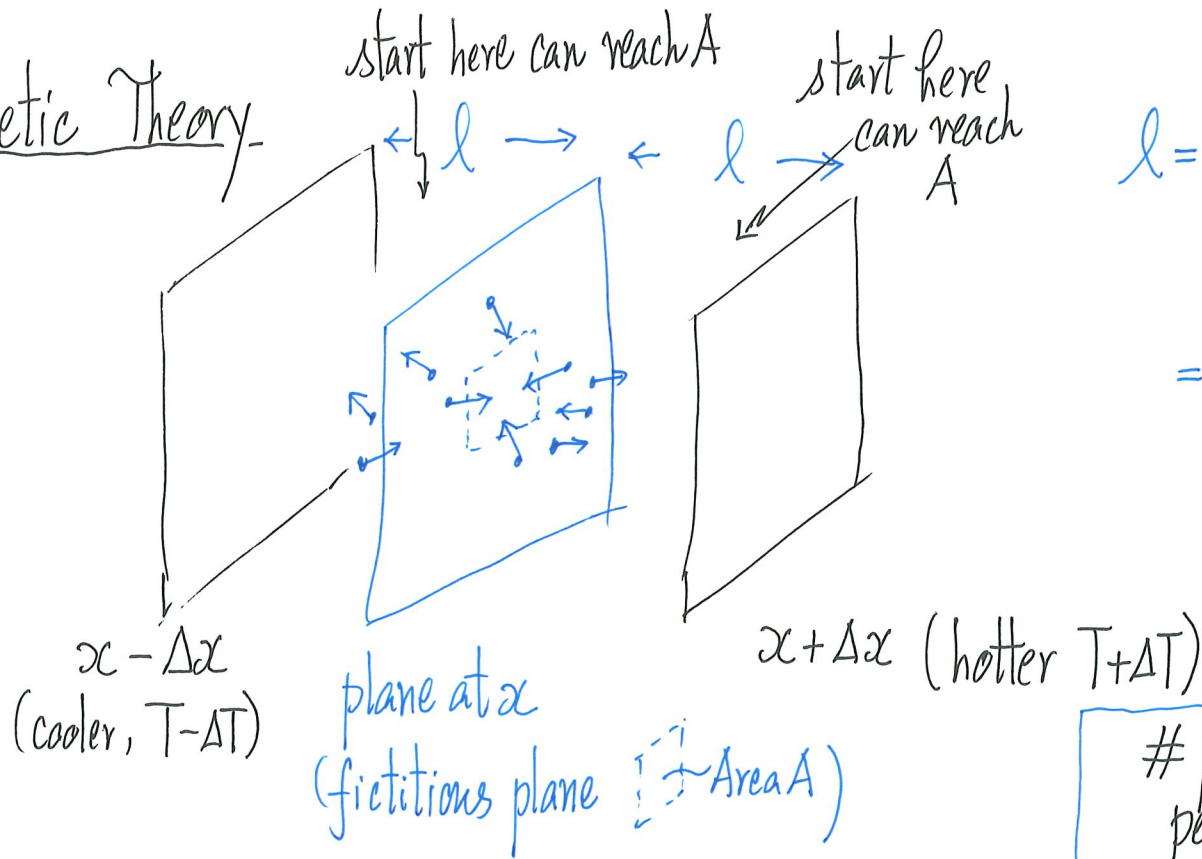
$$\frac{dQ}{dt} \propto \left(-\frac{dT}{dx} \right) \quad k = \text{response function}$$

response \leftarrow $\frac{dQ}{dt}$
 cause \leftarrow $\left(-\frac{dT}{dx} \right)$

$$\vec{Q} = -k \vec{\nabla} T \quad (36a)$$

heat flux (heat flow per area per time) \leftarrow \vec{Q}
 gradient of temperature \leftarrow $\vec{\nabla} T$

Kinetic Theory



l = mean free path of particles
 phonons in our context
 = distance travelled between collisions

$$\left(\frac{dQ}{dt}\right)_{\text{hot} \rightarrow \text{cold}} = a \cdot n(T+\Delta T) \cdot v \cdot A \cdot \overline{u_{th}}(T+\Delta T)$$

↑
average thermal energy of particles

Heat flow per time due to particles crossing A from hotter side at $x+\Delta x$
 l away

$$\left(\frac{dQ}{dt}\right)_{\text{cold} \rightarrow \text{hot}} = a \cdot n(T-\Delta T) \cdot v \cdot A \cdot \overline{u_{th}}(T-\Delta T)$$

Heat flow per time due to particles crossing A from colder side at $x-\Delta x$

particles crossing unit area per second

$$= a \cdot n \cdot v$$

↑ $0(1)$ constant ↑ particle number density ($n(T)$) ↑ some average speed for phonons
 $v_{ph} \approx v_s$
 ↑
 doesn't vary with T

Net rate of energy flow

$$\frac{dQ}{dt} = \left(\frac{dQ}{dt}\right)_{\text{hot} \rightarrow \text{cold}} - \left(\frac{dQ}{dt}\right)_{\text{cold} \rightarrow \text{hot}} = a \cdot v \cdot A \left[\overline{n u_{\text{th}}}(T+\Delta T) - \overline{n u_{\text{th}}}(T-\Delta T) \right]$$

For small ΔT [across Δx]

$$\underbrace{\frac{dQ}{dt}}_{\text{to the left}} = 2 a v A \left[\frac{d}{dT}(n u_{\text{th}}) \right] \Delta T$$

a representative
value of $n u_{\text{th}}$
at hotter side
at $T+\Delta T$

But $\Delta T =$ change in temperature over a distance $\Delta x = l$
 $\therefore \Delta T = \left| \frac{dT}{dx} \right| \cdot l$

$$\therefore \frac{dQ}{dt} = A \cdot \underbrace{(2 a v l \frac{d}{dT}(n u_{\text{th}}))}_{K} \cdot \left(-\frac{dT}{dx}\right) \quad (38)^+$$

$K =$ thermal conductivity

+ This is typical of linear response, the response function K is given in terms of quantities independent of $\left(-\frac{dT}{dx}\right)$.

$$K \propto v \cdot l \cdot C \quad (39)$$

\uparrow typical speed of particles
 \uparrow mean free path
 \uparrow specific heat

$$C = \frac{d}{dT} (\overline{nu} u_{th})$$

\uparrow # per volume
 \uparrow energy per particle

Prefactor "1/3" when things are done more carefully.

Now our context is a Phonon Gas

$$v_{ph} \approx \text{constant} \quad (\omega = v_0 q)$$

$$l_{ph} = v_{ph} \cdot \tau_{ph} \leftarrow \text{time between collisions}$$

High temp: phonon-phonon collisions dominant
 (many phonons, $n_{ph}(T)$)

Low temp: phonon-impurity, phonon-sample boundary scatterings

Phonon-phonon scattering

▪ Must due to anharmonic terms [harmonic \Rightarrow phonons are independent]

▪ terms $\sim u \cdot u \cdot u$ [recall: $u_{\vec{R}} \sim \sum_{\vec{q}} (\dots) (\hat{b}_{\vec{q}} e^{i\vec{q} \cdot \vec{R}} + \hat{b}_{\vec{q}}^{\dagger} e^{-i\vec{q} \cdot \vec{R}})$]

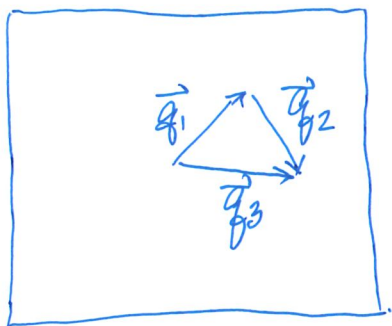
\therefore many terms involving $\vec{q}_1, \vec{q}_2, \vec{q}_3$ in exponential terms

$$\vec{q}_1 + \vec{q}_2 = \vec{q}_3 + \vec{G} \quad ; \quad \hbar\omega_1 + \hbar\omega_2 = \hbar\omega_3$$

$$(\hbar\vec{q}_1 + \hbar\vec{q}_2 = \hbar\vec{q}_3 + \hbar\vec{G}) \quad \begin{matrix} \uparrow & \uparrow & \uparrow \\ \omega_1(\vec{q}_1) & \omega_2(\vec{q}_2) & \omega_3(\vec{q}_3) \end{matrix}$$

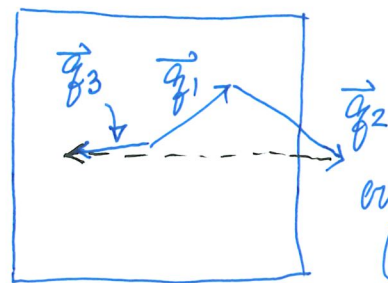
$\vec{G} = 0 \Rightarrow$ Normal Processes

$\vec{G} \neq 0 \Rightarrow$ Umklapp Processes



B.Z.

destroying \vec{q}_1, \vec{q}_2 and creating \vec{q}_3



out of B.Z. (translates back by a \vec{G})

$\vec{q}_3 \sim$ in direction very different from \vec{q}_1, \vec{q}_2 (thermal resistance)

$$\underline{K(T)} : K \sim v_{ph} \cdot l_{ph} \cdot C_{ph}$$

$$\underline{\text{High Temp.}} : C_{ph} \sim \text{constant} \sim k \quad (\text{Dulong-Petit})$$

$$l_{ph} \sim v_{ph} \cdot \tau_{ph} ; \tau_{ph} \text{ dominated by Umklapp ph-ph scattering}$$

$$\sim \frac{1}{T}$$

$$\frac{1}{\tau_{ph}} \sim N_{\text{phonon}} \sim \frac{kT}{\hbar \omega_D} \sim T$$

$$K(T \gg \theta_D) \sim \frac{1}{T}$$

$$(\text{sometimes observed to be } \sim \frac{1}{T^x} \text{ (} x > 1 \text{)})$$

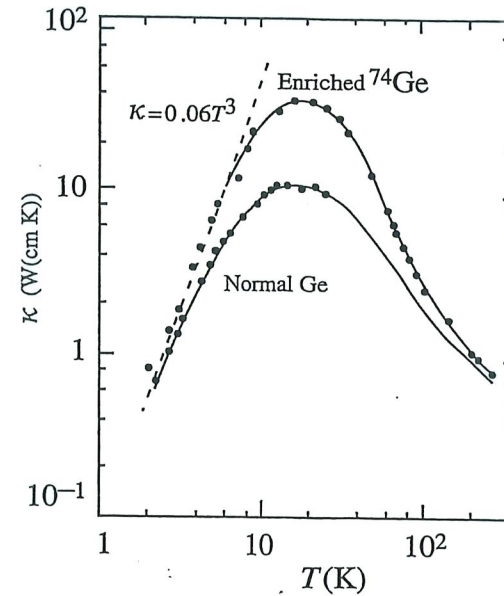
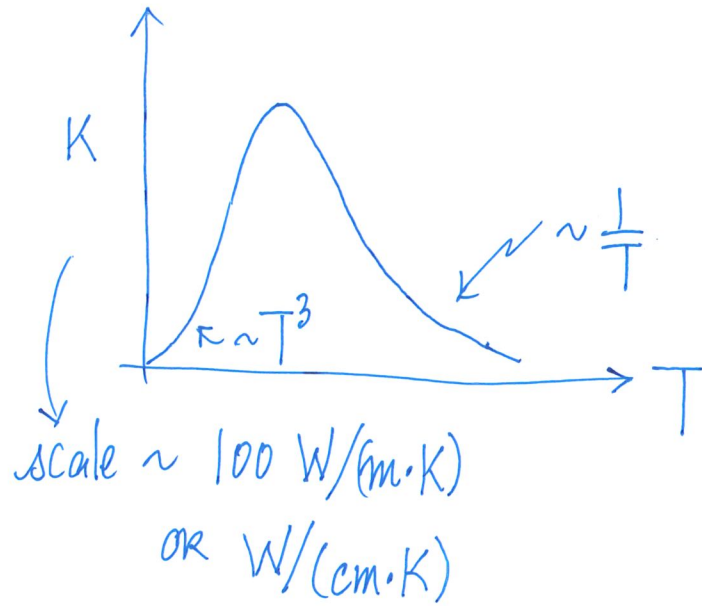
Very low Temp

$l_{ph} \sim$ very long for phonon-phonon scattering

\therefore other lengths take over, e.g. $l_{ph} \sim$ sample size

$$C_{ph} \sim T^3$$

$$\Rightarrow K \sim T^3$$

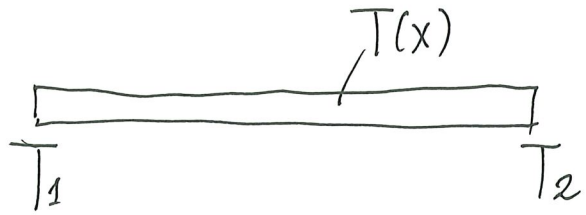


Thermal conductivity of isotopically enriched Ge versus temperature

Remark

- Proper treatment is to apply Boltzmann Equation for a generalized phonon distribution function.

$$\text{Equilibrium } n(\vec{q}) = n_{\vec{q}} = \frac{1}{e^{\hbar\omega(\vec{q})/kT} - 1}$$



$$n(\vec{q}, x, t) d^3q dx$$

= # phonons in d^3q at \vec{q} and in x to $x+dx$ at time t

Boltzmann Equation

Steady state $\left(\frac{\partial n}{\partial t}\right)_{\text{driven}}$
 e.g. $\vec{q} \cdot \nabla T$

$$+ \left(\frac{\partial n}{\partial t}\right)_{\text{scattering}} = 0$$

Valid for weak or strong driving "forces"
 (both linear and nonlinear response)